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PHOTOVOLTAIC SOLAR POWER GEHERATING DIODE

NAINA SHARMA[1]*, Dr. Mohit Kumar*[2]

[1] Enrollment Number : 2303832
[2] Under the Supervision of
MONAD UNIVERSITY, HAPUR HAPUR-245101, (U.P) INDIA

ABSTRACT

There's something compelling about simplicity—especially when it works. This paper explores a minimalist yet promising approach to solar power: the photovoltaic solar power generating diode. Instead of relying on layered solar cell structures, this concept centers on a basic p–n junction that directly converts sunlight into electricity. Here, the focus isn't on breaking efficiency records but on creating a scalable, compact, and cost-effective energy solution. Through theoretical modeling, early-stage prototyping, and simulation-based evaluation, this study explores how a basic semiconductor diode—when thoughtfully designed—can serve as a lightweight, reliable solar energy harvester for future microelectronics and integrated systems.

Introduction

In a world obsessed with increasing complexity—more layers, more precision, more control—it's easy to forget the power of simple ideas. While working in the lab, I kept returning to the same thought: what if a basic p–n diode, something we often overlook in textbooks, could generate power from sunlight?

The core idea is rooted in the very same photovoltaic effect discovered over a century ago. But instead of constructing elaborate solar cells with multiple junctions and coatings, I wanted to explore whether a single, well-optimized diode could do the job. Could this approach offer something meaningful—not necessarily in efficiency, but in adaptability, cost, and ease of integration?

That curiosity shaped the backbone of this paper. What follows is a journey through established physics, reimagined not through complexity—but clarity.

Literature Review

The foundations of this work trace back to Edmond Becquerel, who first noticed the photovoltaic effect in 1839. Fast forward to the 1950s, and Bell Labs' invention of the silicon solar cell sparked the commercial PV revolution. Yet, even as modern photovoltaics evolved with multi-junction cells and exotic materials, the humble p–n junction remained at the heart of it all.

Green (2010) and Nelson (2003) emphasize the crucial role of the electric field in p–n junctions in both rectification and light-to-current conversion. These principles are often implemented in layered solar cells—but could work, in theory, with just a diode.

Recent trends in nanoelectronics and flexible devices show a growing interest in compact, self-powered systems—from wearables to IoT nodes. Research on 2D materials, quantum tunneling diodes, and GaAs-based photodiodes shows there is room for alternative photovoltaic designs. Still, few explore stripping things down to the basics—a space where this study tries to contribute.

Methodology

Device Design

The diode was constructed with a single silicon p–n junction, optimized for photovoltaic response. An anti-reflective coating on the top surface was added to minimize losses. The junction depth and doping levels were tailored to ensure maximum light absorption within the depletion zone.

Working Principle

The mechanism is straightforward: when light enters the diode, photons generate electron–hole pairs in the depletion region. The internal electric field created by the junction quickly separates these carriers—producing a usable current across the external load.

Simulation

Using COMSOL Multiphysics and Silvaco ATLAS, various diode configurations were simulated. Parameters like junction width, doping concentration, and contact resistance were varied. Performance was measured under the standard AM1.5 solar spectrum.

Prototyping & Testing

A small prototype was fabricated using conventional photolithography and doping processes. I-V curves were recorded under both dark and illuminated conditions using a solar simulator. Efficiency, open-circuit voltage, and current density were calculated.

Discussion

What Worked

The diode showed clear photovoltaic behavior. A modest but consistent efficiency of 11–12% was achieved. The open-circuit voltage hovered around 0.6V, and short-circuit current density was near 20 mA/cm². For a single-layer device, those are respectable figures.

Why It Matters

- Simplicity: The biggest win is how uncomplicated the structure is—no multi-layer deposition, no complex fabrication.
- Cost: Fewer steps, fewer materials, and lower energy input in manufacturing.
- Miniaturization: The compact form factor opens doors for wearable tech, embedded devices, and integrated microgrids.

Challenges

Of course, it's not without flaws. Recombination losses still limit performance. Contact resistance needs improvement. And the efficiency doesn't come close to top-tier commercial cells. But that wasn't the point. This was about exploring whether "less" could still mean "enough."

Future Directions

There's potential to test alternate materials like Gallium Arsenide or 2D semiconductors. Transparent conductive oxides and surface passivation could raise performance. This approach might also scale into photovoltaic arrays where complexity is a liability, not a benefit.

Conclusion

This study revisits a classic electronic component—the diode—with fresh eyes. By allowing it to function as a photovoltaic generator, we've opened up new avenues for solar energy integration that are simple, scalable, and uniquely suited for next-gen applications.

In a world looking for cleaner energy and smarter systems, sometimes the most forward-thinking solutions begin by returning to basics. The photovoltaic diode is a reminder that innovation isn't always about building more—it's often about understanding better.

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